

HER1001G thru HER1008G



Pb Free Plating Product

10.0 Ampere Heatsink Dual Common Cathode High Efficiency Rectifiers

**Features**

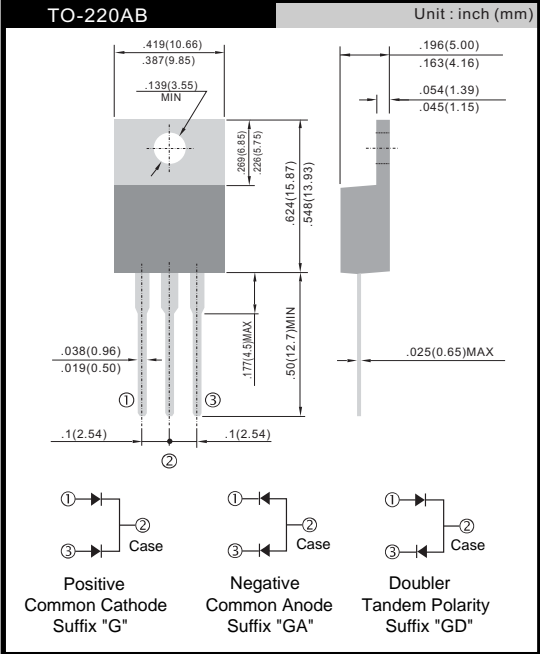
- \* Fast switching for high efficiency
- \* Low forward voltage drop
- \* High current capability
- \* Low reverse leakage current
- \* High surge current capability

**Application**

- \* Automotive Inverters/Solar Inverters
- \* Plating Power Supply, SMPS and UPS
- \* Car Audio Amplifiers and Sound Device Systems

**Mechanical Data**

- \* Case: Heatsink TO-220AB
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Terminals: Solderable per MIL-STD-202 method 208
- \* Polarity: As marked on diode body
- \* Mounting position: Any
- \* Weight: 2.1 gram approxiamtely



**Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified.  
 Single phase, half wave, 60 Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%

Type Number	Symbol	HER 1001G	HER 1002G	HER 1003G	HER 1004G	HER 1005G	HER 1006G	HER 1007G	HER 1008G	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current	$I_{F(AV)}$	10								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	$I_{FSM}$	125								A
Maximum Instantaneous Forward Voltage (Note 1) @ 5 A	$V_F$	1.0			1.3		1.7			V
Maximum DC Reverse Current @ $T_A=25^\circ C$ at Rated DC Blocking Voltage @ $T_A=125^\circ C$	$I_R$	10								uA
		400								uA
Maximum Reverse Recovery Time (Note 2)	$T_{rr}$	50				80				nS
Typical Junction Capacitance (Note 3)	$C_j$	60				40				pF
Typical Thermal Resistance	$R_{\theta JC}$	1.5								$^\circ C/W$
Operating Temperature Range	$T_J$	- 65 to + 150								$^\circ C$
Storage Temperature Range	$T_{STG}$	- 65 to + 150								$^\circ C$

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle  
 Note 2: Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, IRR=0.25A  
 Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (HER1001G thru HER1008G)

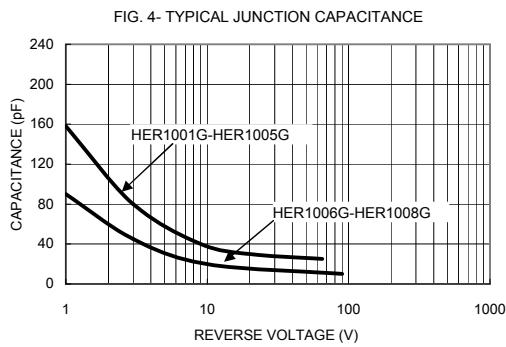
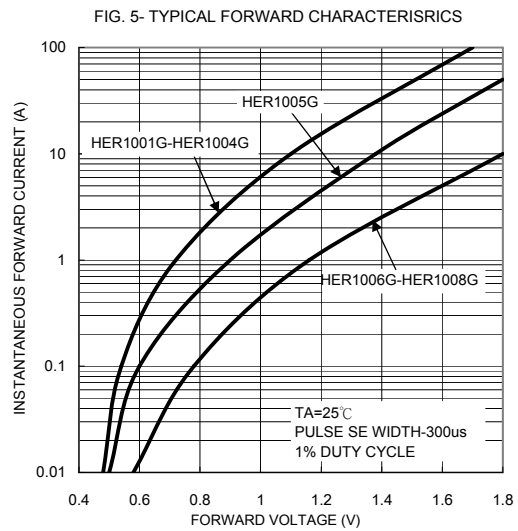
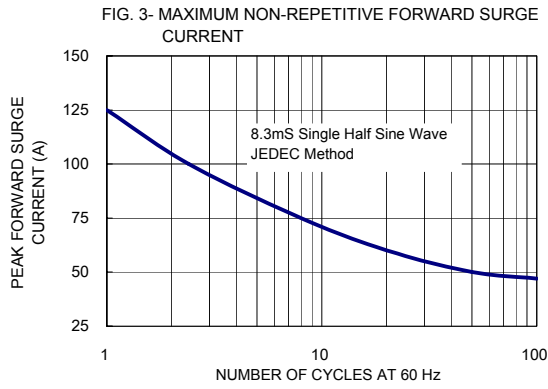
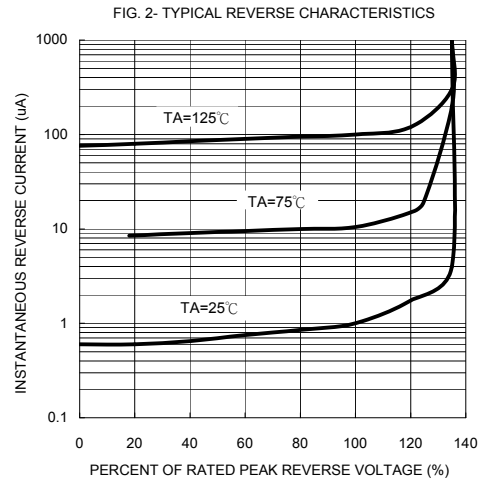
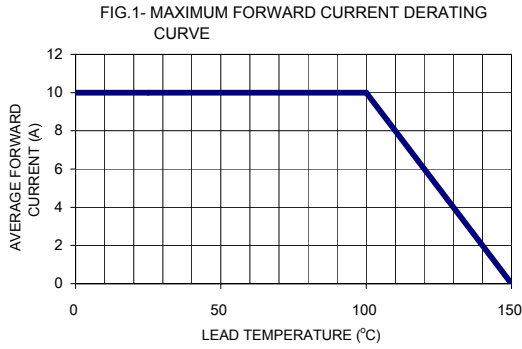


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

